BUT211X

GENERAL DESCRIPTION

Enhanced performance, new generation, high speed switching npn transistor in a plastic full-pack envelope specially suited for high frequency electronic lighting ballast applications.

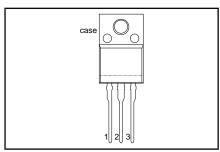
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V _{CESM}	Collector-emitter voltage peak value	$V_{BF} = 0 \text{ V}$	-	850	V
V _{CEO}	Collector-emitter voltage (open base)		-	400	V
I _C	Collector current (DC)		-	5	Α
1 1	Collector current peak value		-	10	Α
P _{tot}	Total power dissipation	T _{hs} ≤ 25 °C	-	32	W
V _{CEsat}	Collector-emitter saturation voltage	$I_{\rm C} = 3.0 \text{ A}; I_{\rm B} = 0.3 \text{ A}$	-	2.0	V
t,	Inductive fall time	$I_{Con} = 3.0 \text{ A}$; $I_{Bon} = 0.3 \text{ A}$	-	0.1	μs

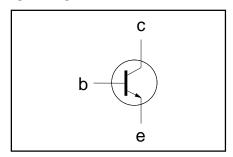
PINNING - SOT186A

PIN	DESCRIPTION	
1	base	
2	collector	
3	emitter	
case	isolated	

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum Rating System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CESM}	Collector-emitter voltage peak value	$V_{BE} = 0 \text{ V}$	-	850	V
V_{CEO}	Collector-emitter voltage (open base)		-	400	V
I _C	Collector current (DC)		-	5	Α
I _{CM}	Collector current peak value		-	10	Α
I _B	Base current (DC)		-	2	Α
I _{BM}	Base current peak value		-	4	Α
P _{tot}	Total power dissipation	$T_{hs} \leq 25 ^{\circ}C$	-	32	W
T _{stq}	Storage temperature		-65	150	°C
	Junction temperature		-	150	°C

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
R _{th j-hs}	Junction to heat sink		-	3.95	K/W
R _{th i-a}	Junction to ambient	in free air	-	55	K/W

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ISOLATION LIMITING VALUE & CHARACTERISTIC

 T_{hs} = 25 $^{\circ}$ C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{isol}	R.M.S. isolation voltage from all three terminals to external heatsink	f = 50-60 Hz; sinusoidal waveform; R.H. ≤ 65%; clean and dustfree	ı		2500	>
C _{isol}	Capacitance from T2 to external heatsink	f = 1 MHz	-	10	-	pF

STATIC CHARACTERISTICS

 T_{hs} = 25 $^{\circ}$ C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CES}	Collector cut-off current 1	$egin{aligned} V_{\text{BE}} &= 0 \ \text{V}; \ V_{\text{CE}} &= V_{\text{CESMmax}} \ V_{\text{BE}} &= 0 \ \text{V}; \ V_{\text{CE}} &= V_{\text{CESMmax}}; \end{aligned}$	-	-	1.0	mA
I _{CES}		$V_{BE} = 0 \text{ V}; V_{CE} = V_{CESMmax};$ $T_i = 125 \text{ °C}$	-	-	2.0	mA
I _{EBO}	Emitter cut-off current	$V_{EB} = 9.0 \text{ V}; I_{C} = 0 \text{ A}$	-	-	10.0	mA
V _{CEOsust}	Collector-emitter sustaining voltage	$I_{B} = 0 \text{ A}; I_{C} = 100 \text{ mA};$	400	-	-	V
V_{CEsat}	Collector-emitter saturation voltage	$I_{C} = 25 \text{ mH}$ $I_{C} = 3.0 \text{ A}; I_{B} = 0.3 \text{ A}$	_	0.8	2.0	V
V _{BEsat}	Base-emitter saturation voltage	$I_{C} = 4.0 \text{ A}; I_{B} = 0.6 \text{ A}$	-	-	1.3	V
h _{FE}	DC current gain	$I_{\rm C} = 1.0 \text{ A}; V_{\rm CE} = 2 \text{ V}$	13	23	30	
h _{FE}		$I_{C} = 4.0 \text{ A}; V_{CE} = 2 \text{ V}$	6	10.5	-	
h _{FE}		$I_{\rm C} = 3.0 \text{ A}; V_{\rm CE} = 2 \text{ V}$	10	13	-	

DYNAMIC CHARACTERISTICS

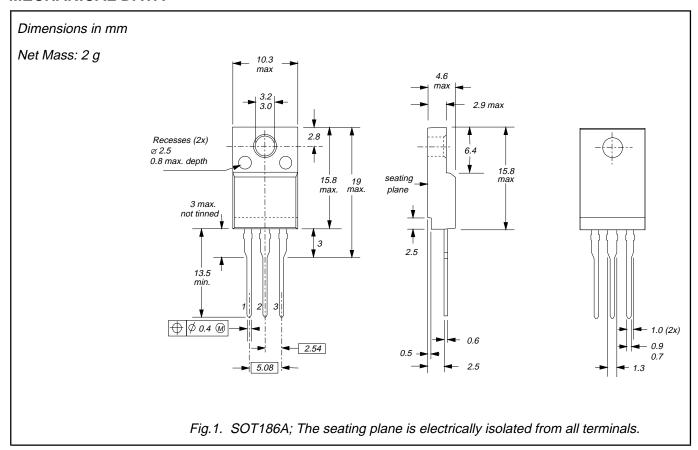
 $T_{hs} = 25$ °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
t _s	Switching times resistive load Turn-off storage time Turn-off fall time	$I_{Con} = 3.0 \text{ A}; I_{Bon} = 0.3 \text{ A}; -I_{Boff} = 0.6 \text{ A}$	1.5 0.5	2.0 0.8	μs μs
	Switching times inductive load	$I_{Con} = 3.0 \text{ A}; I_{Bon} = 0.3 \text{ A}; L_{B} = 1 \mu\text{H}; $ - $V_{BB} = 5 \text{ V}$			
t _s	Turn-off storage time Turn-off fall time	55	1.0 60	1.2 100	μs ns
		$I_{Con} = 3.0 \text{ A}; I_{Bon} = 0.3 \text{ A}; L_{B} = 1 \mu\text{H}; -V_{BB} = 5 \text{ V}; T_{i} = 100 ^{\circ}\text{C}$			
t _s t _f	Turn-off storage time Turn-off fall time	55 , ,	1.1 120	1.4 250	μs ns

¹ Measured with half sine-wave voltage (curve tracer).

BUT211X

MECHANICAL DATA



- Refer to mounting instructions for F-pack envelopes.
 Epoxy meets UL94 V0 at 1/8".

BUT211X

DEFINITIONS

Data sheet status					
This data sheet contains target or goal specifications for product development.					
This data sheet contains preliminary data; supplementary data may be published later.					
This data sheet contains final product specifications.					
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Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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